

## **Precision Quad SPDT Analog Switch**

#### **DESCRIPTION**

The DG333A, DG333AL consist of four independently controlled single-pole double-throw analog switches. These monolithic switch is designed to control analog signals with a high degree of accuracy. The DG333A, DG333AL minimize measurement errors by offering low on-resistance (25  $\Omega$  typ), low leakage (20 pA typ.) and low charge injection performance. The DG333AL features micro-power operation (< 1 μW typ.). This is ideal for battery operated systems. Pin 15 is not connected on the DG333A.

An improved charge injection compensation design minimizes switching transients. These switches can handle up to  $\pm$  22 V signals and have an improved continuous current of 30 mA.

The DG333A, DG333AL is fabricated in Vishay Siliconix's proprietary HVSG-2 CMOS process, resulting in higher speed and lower power consumption. An epitaxial layer prevents latchup. Each switch conducts equally well in both directions when on. When off, they block voltages up to the power-supply levels.

#### **FEATURES**

- ± 22 V supply voltage range
- TTL and CMOS compatible logic
- Low on-resistance (25  $\Omega$ )
- On-resistance matched between channels ( $< 2 \Omega$ )
- Flat on-resistance over analog signal range ( $\Delta$  < 3  $\Omega$ )
- Low charge injection (1 pC)
- Low leakage (0.2 nA)
- Fast switching (175 ns)
- Single-supply operation (5 V to 40 V)
- ESD tolerance > 2 kV per 3015.x
- Low power (< 1 µA) DG333A, DG333AL

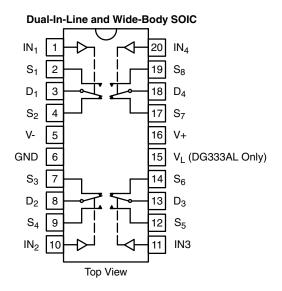
#### **BENEFITS**

- Rail-to-rail analog signal range
- Simple logic interface
- High precision and accuracy
- Minimal transients
- Low distortion
- Reduced power consumption
- Improved reliability
- Break-before-make switching action

#### **APPLICATIONS**

- Audio switching
- Test equipment
- Portable instrumentation
- Communication systems
- PBX, PABX
- Computer peripherals
- Mass storage systems
- Switched-capacitor networks
- Battery-powered systems

#### **FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION**



TRUTH TABLE						
Logic	SW1, 4, 5, 8 Normally Open	SW2, 3, 6, 7 Normally Closed				
0	OFF	ON				
1	ON	OFF				

Logic "0" ≤ 0.8 V Logic "1" ≥ 2.4 V

ORDERING INFORMATION				
Temp. Range	Package	Part Number <sup>a</sup>		
	20-Pin Plastic DIP	DG333ADJ-E3		
	20-1 III I lastic Dii	DG333ALDJ-E3		
- 40 °C to 85 °C	20-Pin Wide-Body SOIC	DG333ADW-E3		
	(shipped in tubes)	DG333ALDW-E3		
	20-Pin Wide-Body SOIC	DG333ADW-T1-E3		
	(shipped in tape and reel)	DG333ALDW-T1-E3		
	20-Pin TSSOP	DG333ADQ-T1-E3		
	(shipped in tape and reel)	DG333ALDQ-T1-E3		

a. For standard tin/lead external termination, remove the "-E3" from the ordering part number.



ABSOLUTE MAXIMUM RATINGS						
Parameter		Limit	Unit			
Voltages Referenced V+ to V-		44				
GND		30				
V+ to GND		30	V			
Digital Inputs <sup>a</sup> V <sub>S</sub> , V <sub>D</sub>		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first				
Current, Any Terminal		30	mA			
Peak Current S or D (Pulsed at 1 ms, 10 % Duty Cycle Max.)		100	IIIA			
Storage Temperature		- 65 to 125	°C			
Power Dissipation (Package) <sup>b</sup>	20-Pin Plastic DIP <sup>c</sup>	890	mW			
	20-Pin Wide SOIC <sup>d</sup>	800	11177			

- a. Signals on S<sub>X</sub>, D<sub>X</sub>, or IN<sub>X</sub> exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 12 mW/°C above 75 °C.
- d. Derate 10 mW/°C above 75 °C.

### **SCHEMATIC DIAGRAM** (Typical Channel)

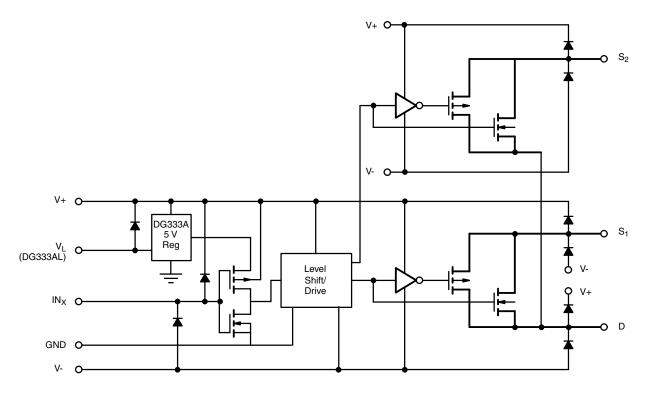


Figure 1.



		Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V	Temp. <sup>a</sup>	Limits D Suffix - 40 °C to 85 °C			
Parameter	Symbol	$V_{IN} = 2.4 \text{ V or } 0.8 \text{ V}^{e}$		Min.b	Typ.c	Max.b	Unit
Analog Switch							•
Analog Signal Range <sup>d</sup>	V <sub>ANALOG</sub>		Full	V-		V+	V
Channel On-Resistance	B	$I_S = -10 \text{ mA}, V_D = \pm 10 \text{ V}$	Room Full		25	45 90	
On-Resistance Flatness	R <sub>DS(on)</sub>	$I_S = -10 \text{ mA}, V_D = \pm 5 \text{ V}$ V+ = 16.5 V, V- = -16.5 V	Room Full			3 5	Ω
R <sub>DS(on)</sub> Match Between Channels <sup>f</sup>	$\Delta R_{DS(on)}$	$I_S = -10 \text{ mA}, V_D = \pm 10 \text{ V}$	Room Full			2 4	
Source Off Leakage Current	I <sub>S(off)</sub>	V <sub>D</sub> = 15.5 V, V <sub>S</sub> = 15.5 V V+ = 16.5 V, V- = - 16.5 V	Room Hot	- 0.25 - 20		0.25 20	nA
Channel On Leakage Current	I <sub>D(on)</sub>	$V_D = \pm 15.5 \text{ V}, V_{S(open)} = \pm 15.5 \text{ V}$ $V_{+} = 16.5 \text{ V}, V_{-} = -16.5 \text{ V}$	Room Hot	- 0.75 - 60		0.75 60	IIA
Digital Control							
Input Voltage High	$V_{INH}$		Full	2.4			V
Input Voltage Low	$V_{INL}$		Full			0.8	v
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>INH</sub> or V <sub>INL</sub>	Full	- 1		1	μΑ
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	See switching time test circuit see figure 2	Room			175	
Turn-Off Time	t <sub>OFF</sub>	See switching time test circuit see figure 2	Room			145	ns
Break-Before-Make Time Delay	t <sub>D</sub>	See figure 3	Room	5			
Charge Injection <sup>d</sup>	Q	$C_L$ = 10 nF, $V_{gen}$ = 0 V, $R_{gen}$ = 0 $\Omega$	Room			10	рC
Off-Isolation	OIRR	$R_L = 75 \Omega, C_L = 5 pF$	Room		72		dB
Channel-to-Channel Crosstalk	X <sub>TALK</sub>	$V_D = 2.3 V_{RMS}$ , f = 1 MHz	Room		80		uБ
Off Capacitance	C <sub>OFF</sub>	f = 1 MHz, V <sub>S</sub> = 0 V	Room		8		pF
Channel On Capacitance	C <sub>ON</sub>	1 - 1 WH 12, V S - 0 V	Room		12		рг
Power Supplies							
Positive Supply Current	l+	DG333A: V <sub>IN</sub> = 0 or 5 V	Room			200	
Negative Supply Current	I-	20007 VIN = 0 01 0 V	Room	- 1			
Positive Supply Current	l+		Room			1	μΑ
Logic Supply Current	ΙL	DG333AL: $V_{IN} = 0$ or 5 V, $V_L = 5$ V	Room			1	
Negative Supply Current	I-		Room	- 1			
Supply Voltage Range	V+/V-		Full	± 4		± 22	V



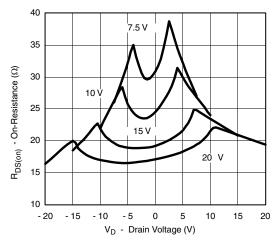
SPECIFICATIONS (Unip	olar Suppli	es)					
		Test Conditions Unless Otherwise Specified		Limits D Suffix - 40 °C to 85°C			
Parameter	Symbol	V+ = 12 V, V- = 0 V T <sub>A</sub> = 25°C	Temp.a	Min.b	Typ.c	Max.b	Unit
Analog Switch							
Analog Signal Range <sup>d</sup>	V <sub>ANALOG</sub>		Full	V-		V+	V
Channel On-Resistance	R <sub>DS(on)</sub>	I <sub>S</sub> = - 10 mA, V <sub>D</sub> = 10, 1 V	Room		35	75	Ω
Source Off Leakage Current	I <sub>S(off)</sub>	V <sub>D</sub> = 11 V, V <sub>S(open)</sub> = 1 V	Room			0.25	
Channel On Leakage Current	I <sub>D(on)</sub>	$V_D = 11 \text{ V}, V_{S(open)} = 0 \text{ V}$ $V_D = 1 \text{ V}, V_{S(open)} = \text{V}+$	Room			0.75	nA
Dynamic Characteristics					_	•	
Turn-On Time	t <sub>ON</sub>	Con quitobing time toot airquit and figure 2	Room		90		
Turn-Off Time	t <sub>OFF</sub>	See switching time test circuit see figure 2	Room		45		ns
Break-Before-Make Time Delay	t <sub>D</sub>	See figure 3	Room	5	10		
Power Supplies							
Positive Supply Current	l+	DG333A: V <sub>IN</sub> = 0 or 5 V	Room			200	
Positive Supply Current	1+	D0000A. V <sub>IN</sub> = 0 01 0 V	Room			1	
Positive Supply Current	l+	DG333AL: V <sub>IN</sub> = 0 or 5 V, V <sub>I</sub> = 5 V	Room			1	μΑ
Logic Supply Current	ΙL	DG333AL. V <sub>IN</sub> = 0 01 3 V, V <sub>L</sub> = 3 V	Room			1	
Positive Supply Range	V+		Room	5		40	V

#### Notes:

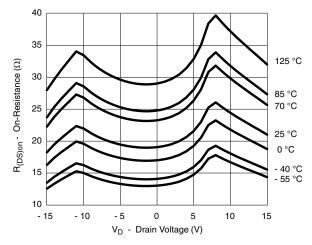
- a. Room = 25  $^{\circ}$ C, Full = as determined by the operating temperature suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- d. Guaranteed by design, not subject to production test.
- e. V<sub>IN</sub> = input voltage to perform proper function.
- f. On-resistance match and flatness are guaranteed only for bipolar supply operation.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25 °C, unless otherwise noted)



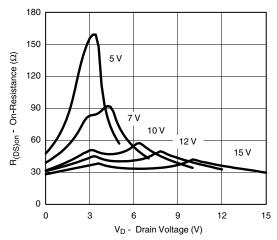
R<sub>DS(on)</sub> vs. V<sub>D</sub> (Dual Supply)



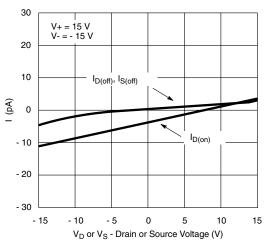
R<sub>DS(on)</sub> vs. V<sub>D</sub> and Temperature (Dual Supply)



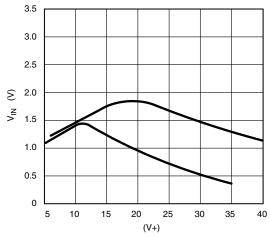
## **TYPICAL CHARACTERISTICS** ( $T_A = 25$ °C, unless otherwise noted)



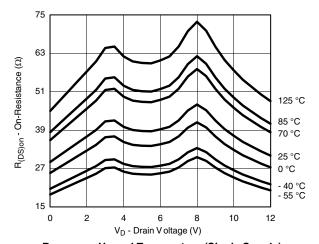
R<sub>DS(on)</sub> vs. V<sub>D</sub> (Single Supply)



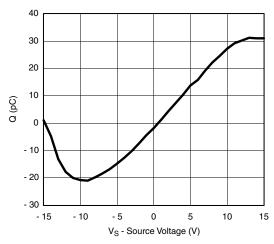
Leakage Currents vs. Analog Voltage



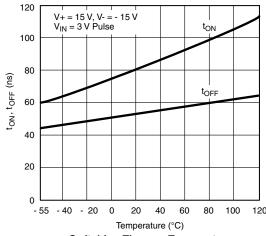
Input Switching Threshold vs. Supply Voltages



 $R_{DS(on)}$  vs.  $V_D$  and Temperature (Single Supply)



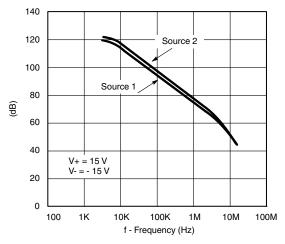
**Drain Charge Injection** 



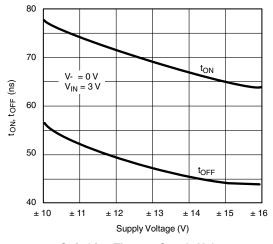
Switching Time vs. Temperature

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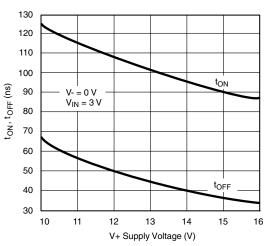
## **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 °C, unless otherwise noted)



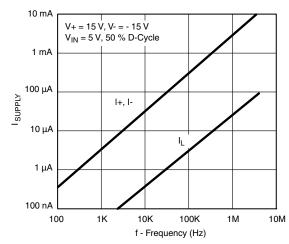
Crosstalk and Off Isolation vs. Frequency



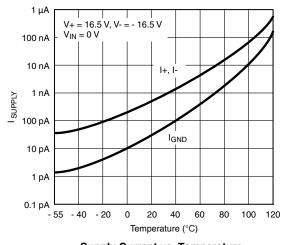
Switching Time vs. Supply Voltages



Switching Time vs. V+



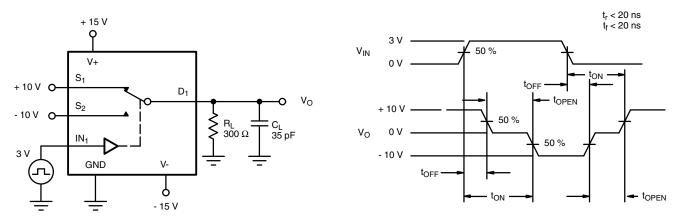
**Power Supply Currents vs. Switching Frequency** 



Supply Current vs. Temperature



#### **TEST CIRCUITS**



Repeat Test for  $\ensuremath{\mathsf{IN}}_2$ ,  $\ensuremath{\mathsf{IN}}_3$  and  $\ensuremath{\mathsf{IN}}_4$ 

Figure 2. Switching Time

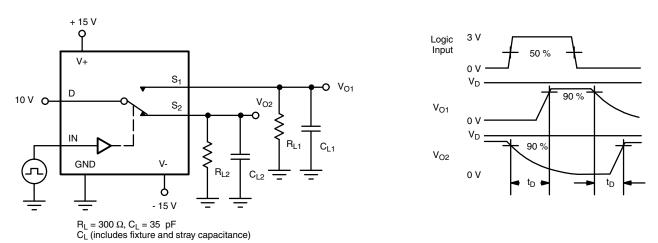


Figure 3. Break-Before-Make

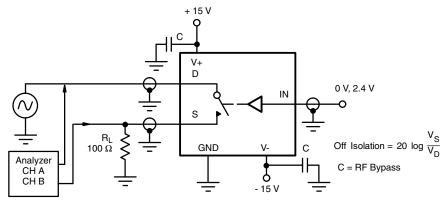


Figure 4. Off Isolation

#### **TEST CIRCUITS**



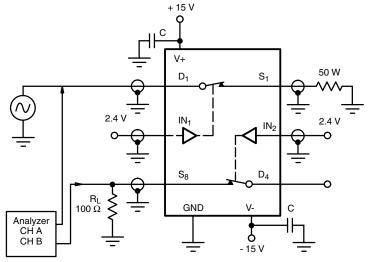


Figure 5. Crosstalk

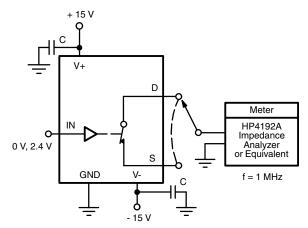


Figure 6. Capacitances

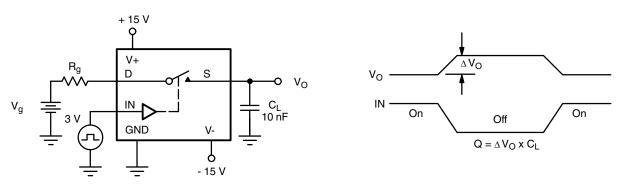


Figure 7. Charge Injection



#### **APPLICATIONS**

#### **Band-Pass Switched Capacitor Filter**

Single-pole double-throw switches are a common element for switched capacitor networks and filters. The fast switching times and low leakage of the DG333A, DG333AL allow for higher clock rates and consequently higher filter operating frequencies. Figure 8 shows two capacitors being switched.

The DG333A, DG333AL is capable of switching four capacitors.

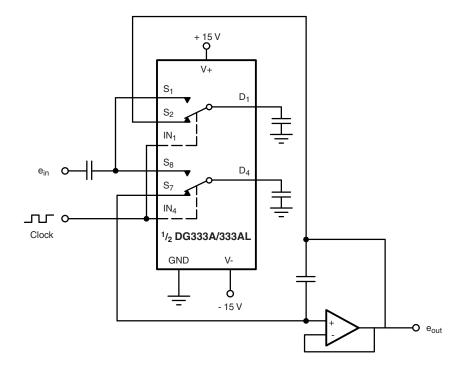
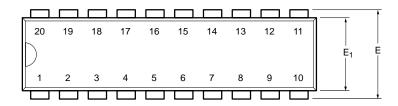


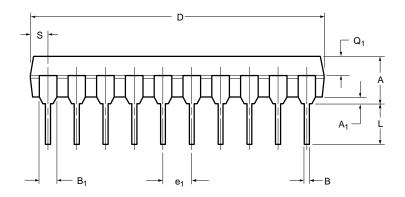
Figure 8. Band-Pass Switched Capacitor Filter

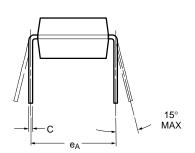
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PDIP: 20-LEAD





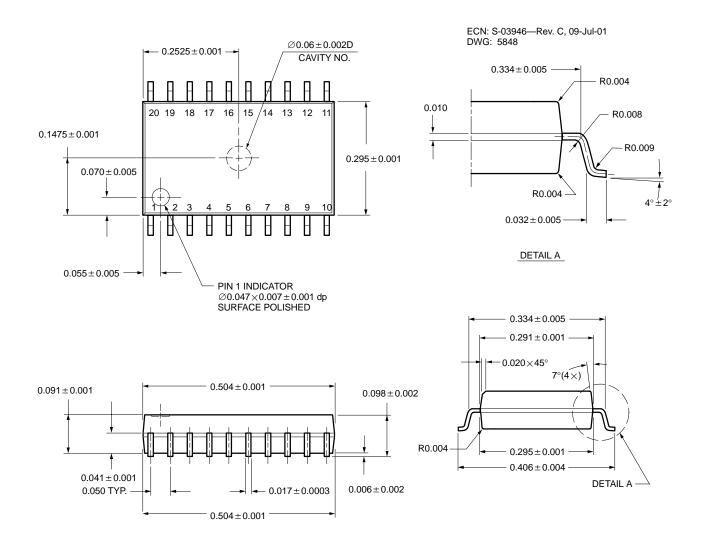


	MILLIN	ILLIMETERS INCHES		HES	
Dim	Min	Max	Min	Max	
Α	3.81	5.08	0.150	0.200	
A <sub>1</sub>	0.38	1.27	0.015	0.050	
В	0.38	0.51	0.015	0.020	
B <sub>1</sub>	0.89	1.65	0.035	0.065	
С	0.20	0.30	0.008	0.012	
D	24.89	26.92	0.980	1.060	
Е	7.62	8.26	0.300	0.325	
E <sub>1</sub>	5.59	7.11	0.220	0.280	
e <sub>1</sub>	2.29	2.79	0.090	0.110	
e <sub>A</sub>	7.37	7.87	0.290	0.310	
L	3.175	3.81	0.123	0.150	
$Q_1$	1.27	2.03	0.050	0.080	
S	1.02	2.03	0.040	0.080	
ECN: S-03946—Rev. B, 09-Jul-01 DWG: 5484					

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## SOIC (WIDE-BODY): 20-LEAD



All Dimensions In Inches.

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